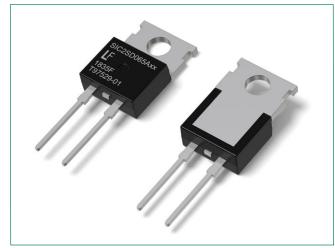
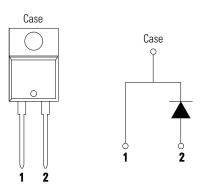
LSIC2SD065A08A 650 V, 8 A SiC Schottky Barrier Diode

HF Rohs 🕫



*Image for reference only, for details refer to Dimensions-Package.

Circuit Diagram TO-220-2L



Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations
- Uninterruptible power supplies

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo =**HF** Halogen Free
- Littelfuse "Pb-free" logo
 Pb-free lead plating

Maximum Ratings

| Characteristics | Symbol | Conditions | Value | Unit | |
|--------------------------------------|-------------------|---|--------------------------|------|--|
| Repetitive Peak Reverse Voltage | V _{RRM} | - | 650 | V | |
| DC Blocking Voltage | V _R | T _J = 25 °C | 650 | V | |
| Continuous Forward Current | | T _c = 25 °C | 23 | A | |
| | I _F | T _c = 135 °C | 10.7 | | |
| | | T _c = 150 °C 8 | |] | |
| Non-Repetitive Forward Surge Current | I _{FSM} | I_{FSM} $T_{c} = 25 \text{ °C}, T_{p} = 10 \text{ ms}, \text{ Half sine pulse}$ | | A | |
| Power Dissipation | P _{Tot} | $T_c = 25 \text{ °C}$ | 88 | W | |
| | | T _c = 110 °C | _c = 110 °C 38 | | |
| Operating Junction Temperature | T | - | -55 to 175 | °C | |
| Storage Temperature | T _{stg} | - | -55 to 150 | °C | |
| Soldering Temperature | T _{SOLD} | - | 260 | °C | |

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GEN2 SiC Schottky Diode

LSIC2SD065A08A, 650V, 8A, TO-220-2L

| Electrical | Characteristics | (Т | =25 °C unless otherwise specified) |
|------------|-----------------|----|------------------------------------|
| LICOUITOUT | onaraotonotio | | |

| Characteristics Syr | Symbol | Conditions | Value | | | Unit |
|--------------------------------|----------------|---|-------|------|------|------|
| Characteristics | Symbol | Conditions | Min. | Тур. | Max. | Onit |
| Forward Voltage | | I _F = 8 A, T _J = 25 °C | - | 1.5 | 1.8 | V |
| | V _F | I _F = 8 A, T _J = 175 °C | - | 1.85 | - | V |
| Reverse Current I _R | 1 | $V_{_{ m R}} = 650 \text{ V}$, $T_{_{ m J}} = 25 \ ^{\circ}\text{C}$ | - | <1 | 50 | |
| | R | $V_{_{ m R}}$ = 650 V , $T_{_{ m J}}$ = 175 °C | - | 15 | - | μΑ |
| Total Capacitance C | | $V_{_{\mathrm{R}}} = 1 \text{ V}, \text{ f} = 1 \text{ MHz}$ | - | 415 | - | pF |
| | С | $V_{_{\mathrm{R}}} = 200 \text{ V}, \text{ f} = 1 \text{ MHz}$ | - | 56 | - | |
| | | $V_{_{ m R}} = 400 \text{ V}, \text{ f} = 1 \text{ MHz}$ | - | 41 | - | |
| Total Capacitive Charge | Q _c | $V_{R} = 400 \text{ V}, Q_{c} = \int_{0}^{V_{R}} C(V) dV$ | - | 29 | - | nC |

| Thormal | Characteristics |
|---------|------------------|
| Incina | Gilaracteristics |

| Characteristics | Symbol | Value | Unit |
|--------------------|------------------|-------|------|
| Thermal Resistance | R _{eJC} | 1.7 | °C/W |

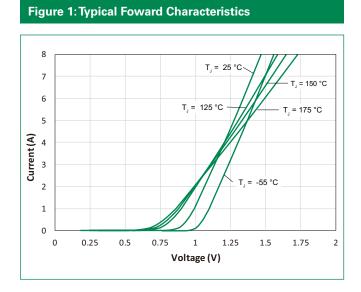
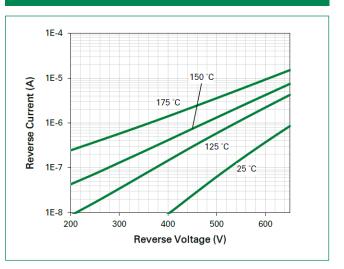


Figure 2: Typical Reverse Characteristics



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GEN2 SiC Schottky Diode LSIC2SD065A08A, 650V, 8A, TO-220-2L

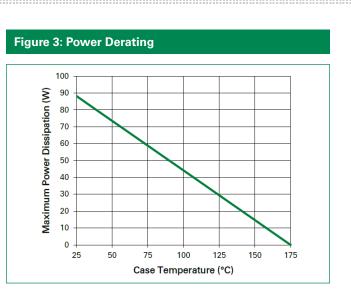


Figure 5: Capacitance vs. Reverse Voltage

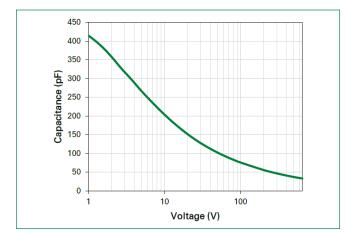


Figure 7: Stored Energy vs. Reverse Voltage

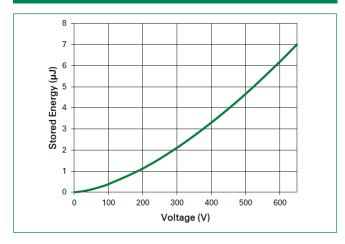


Figure 4: Current Derating

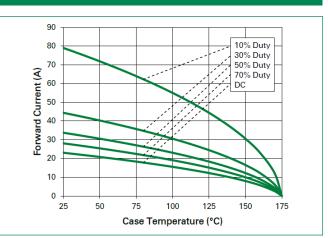


Figure 6: Capacitive Charge vs. Reverse Voltage

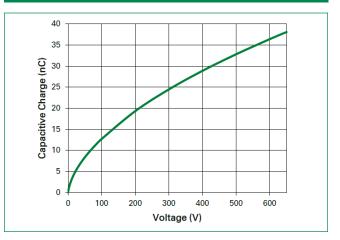
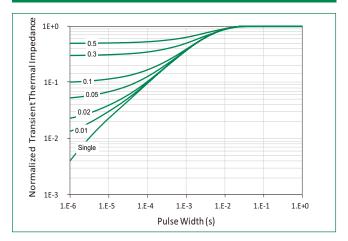


Figure 8: Transient Thermal Impedance



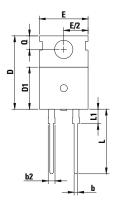
Littelfuse Power

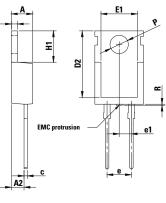
GEN2 SiC Schottky Diode

LSIC2SD065A08A, 650V, 8A, TO-220-2L

Dimensions-Package TO-220-2L

A1



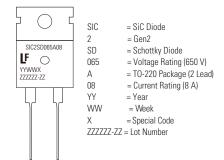


Recommended Hole Pattern



| Ormalial | Millimeters | | | | |
|----------|-------------|-------|-------|--|--|
| Symbol | Min | Nom | Max | | |
| Α | 4.30 | 4.45 | 4.70 | | |
| A1 | 1.14 | 1.27 | 1.40 | | |
| A2 | 2.20 | - | 2.74 | | |
| b | 0.69 | - | 0.90 | | |
| b2 | 1.17 | - | 1.62 | | |
| С | 0.36 | - | 0.60 | | |
| D | 14.90 | - | 15.90 | | |
| D1 | 8.62 | - | 9.40 | | |
| D2 | 12.50 | - | 12.95 | | |
| E | 9.70 | 10.18 | 10.36 | | |
| E1 | 7.57 | 7.61 | 8.30 | | |
| e1 | - | 2.54 | - | | |
| е | 5.03 | 5.08 | 5.13 | | |
| H1 | 6.30 | 6.55 | 6.80 | | |
| L | 12.88 | 13.50 | 14.00 | | |
| L1 | 2.39 | - | 3.25 | | |
| øP | 3.50 | 3.84 | 3.96 | | |
| Q | 2.65 | - | 3.05 | | |
| R | - | - | 0.25 | | |

Part Numbering and Marking System



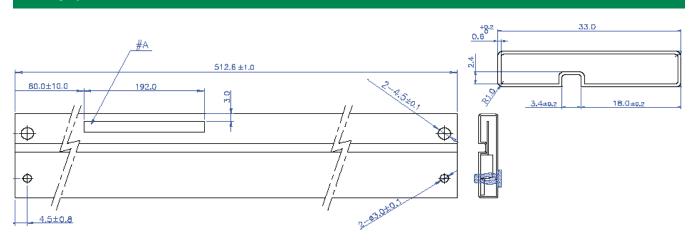
Packing Options

| Part Number | Marking | Packing Mode | M.O.Q |
|----------------|--------------|--------------|-------|
| LSIC2SD065A08A | SIC2SD065A08 | Tube(50pcs) | 1000 |



GEN2 SiC Schottky Diode LSIC2SD065A08A, 650V, 8A, TO-220-2L

Packing Specification (Tube for TO-220-2L)



NOTE]

- TUBE - MATERIAL : PVC / PET (WITH ANTISTATIC COATING)
- COLOR : TRANSPARENCY, RED, YELLO
- MARKING #A : BLACK COLOR, LETTER STYLE : Arial
- Tube Surface Resistance $\div10^{6}{\sim}10^{11}\,\Omega\,/\,\text{square}$
- ESD (Electro Static Discharge) : less than 100 [volts], 6 Months
- CAMBAR : 1.5 MAX
- $\ensuremath{\mathsf{PIN}}$ COLOR : GREEN (ONE PIN MUST BE INSERTED IN LEFT-SIDE OF " $\ensuremath{\mathsf{-ANTISTATIC}}\xspace^{-1}$ and another PIN IS FREE.)

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